

The isotope effect in impure high T_c superconductors.

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The influence of various kinds of impurities on the isotope shift exponent α of high temperature superconductors has been studied. In these materials the dopant impurities, like Sr in $La_{2-x}Sr_xCuO_4$, play different role and usually occupy different sites than impurities like Zn , Fe , Ni etc intentionally introduced into the system to study its superconducting properties. In the paper the in-plane and out-of-plane impurities present in layered superconductors have been considered. They differently affect the superconducting transition temperature T_c . The relative change of isotope shift coefficient, however, is an universal function of T_c/T_{c0} (T_{c0} refers to impurity free system) *i.e.* for angle independent scattering rate and density of states function it does not depend whether the change of T_c is due to in- or out-of-plane impurities. The role of the anisotropic impurity scattering in changing oxygen isotope coefficient of superconductors with various symmetries of the order parameter is elucidated. The comparison of the calculated and experimental dependence of α/α_0 , where α_0 is the clean system isotope shift coefficient, on T_c/T_{c0} is presented for a number of cases studied. The changes of α calculated within stripe model of superconductivity in copper oxides reasonably well describe the data on $La_{1.8}Sr_{0.2}Cu_{1-x}(Fe, Ni)_xO_4$, without any fitting parameters.

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I. INTRODUCTION

It is hard to overestimate the role played by the impurities introduced into otherwise clean superconductor. In response to impurities the superconducting properties of the material change. The changes include superconducting transition temperature, slope and jump of the specific heat, upper critical field, superfluid density, and other thermodynamic and electromagnetic characteristics [1, 2].

One of the parameters of great experimental and theoretical importance is the isotope coefficient α defined by the power law dependence of superconducting transition temperature T_c on the isotope mass M of the element: $T_c \propto M^{-\alpha}$ or $\alpha = -\frac{\partial \ln T_c}{\partial \ln M}$. Illegal variable name. In the BCS model of superconductivity it has been predicted to take on universal value $\alpha_{BCS} = \frac{1}{2}$ and verified experimentally for a number of superconducting elements and simple compounds. In chemically complex multicomponent systems one usually defines the partial coefficients $\alpha_i = -\frac{\partial \ln T_c}{\partial \ln M_i}$, where M_i is the isotope mass of the i -th component. In high temperature superconductors (HTS) typically O^{18} is replaced [3, 4, 5] by O^{16} . This defines so called oxygen isotope coefficient α^O . Limited data are available on the copper isotope shift α^{Cu} in these materials [6, 7].

The effect of impurities introduced into the superconductor on its T_c strongly depends on the symmetry of the order parameter. It is known that non magnetic impurities hardly change T_c of s-wave superconductors (Anderson theorem). On the other hand non magnetic impurities are effective pair breakers in spin singlet d-wave and spin-triplet p- or f- wave superconductors. On the contrary magnetic impurities break time reversal symmetry and strongly affect T_c of all superconductors including

s-wave ones. Changing T_c of the material, impurities indirectly influence all its parameters. In particular this is true for isotope coefficient α . If one finds the change of the superconducting transition temperature due to impurities as $\frac{T_c}{T_{c0}} = f(T_{c0}, \gamma)$, where γ symbolizes all relevant parameters other than T_{c0} itself, then $\frac{\alpha}{\alpha_0} = \frac{\partial \ln T_c}{\partial \ln M} / \frac{\partial \ln T_{c0}}{\partial \ln M}$ can easily be calculated from the explicit knowledge of function $f(T_{c0}, \gamma)$.

It is the purpose of this work to systematically study the effect of disorder on the isotope effect of superconductors by *assuming* that dependence of $\frac{\alpha}{\alpha_0}$ on $\frac{T_c}{T_{c0}}$ can be solely attributed to the effect of impurities. The impurities introduced into the superconductor modify quasi-particle spectrum, interaction parameters and induce pair breaking. This results in a change of the superconducting transition temperature and the isotope coefficient.

The motivation for the present analysis partially comes from the recent experiments which suggest strong effect of electron-phonon coupling on the dynamics of electrons in high-temperature superconductors [8, 9].

The shift of T_c with ionic mass was a crucial experiment to confirm the electron-phonon mechanism of superconductivity in BCS superconductors. Similarly the systematic studies of various isotopic substitutions in HTS are important to understand the role of electron-phonon interaction in these materials. After early experiments with contradictory conclusions [3, 4, 5, 10] it has later been unequivocally established that the oxygen isotope shift α is non-zero, and takes smallest value for optimally doped materials. It increases when one moves into underdoped region.

Our paper extends the recent work of Openov et al. [11], who consider the effect of magnetic and non-magnetic impurities in s-wave and d-wave superconductors.

tors and that of Kresin and coworkers [12] who study the isotope effects in s-wave superconductors doped with magnetic impurities and those showing the dynamic Jahn-Teller and proximity effects. Our aim here is to elucidate the role (in changing α) of the out-of-plane impurities in layered systems and the effect of impurity anisotropy. We also analyze the change of isotope effect due to Zn impurities in the striped phase model of high T_c superconductors. In view of the recent interest in superconductivity and the critical role of impurities played in Sr_2RuO_4 possibly spin-triplet superconductor [13] we shall consider isotope coefficient for p-wave order parameter.

In section 2 we explain the approach and apply it to the layered systems in which carriers mainly reside in active layers (CuO in HTS), while impurities are placed either in the active or in the passive layer. It turns out that due to low angle scattering these out-of-plane impurities have small effect on superconducting transition temperature. However their effect on the isotope coefficient is universal in a sense that α/α_0 depends only on T_c/T_{c0} . In section 3 we analyze the role of in plane anisotropic scatterers in changing transition temperature and the isotope coefficient. Section 4 contains discussion of the results and comparison with experimental data. The predictions of the change of T_c by Zn impurities obtained recently by the stripe theory superconductivity lead to the isotope coefficient, which is calculated in section 5. We end up with conclusions.

II. IN-PLANE AND OUT-OF-PLANE IMPURITIES IN LAYERED SUPERCONDUCTORS

In this section we shall compare the effect of in-plane and out-of-plane impurities in high temperature superconductors on T_c and α . The Hamiltonian of the superconductor containing both kinds of impurities takes the form

$$H = \sum_{\vec{k}\sigma} (\varepsilon_{\vec{k}} - \mu) c_{\vec{k}\sigma}^{\dagger} c_{\vec{k}\sigma} + \sum_{\vec{k}\vec{k}'\sigma} V_{\text{in}}(\vec{k}, \vec{k}') c_{\vec{k}\sigma}^{\dagger} c_{\vec{k}'\sigma} \quad (1)$$

$$+ \sum_{\vec{k}\vec{k}'\sigma} V_{\text{out}}(\vec{k}, \vec{k}') c_{\vec{k}\sigma}^{\dagger} c_{\vec{k}'\sigma} + \sum_{\vec{k}\vec{q}} V_{\vec{k},\vec{q}} c_{\vec{k}\uparrow}^{\dagger} c_{-\vec{k}\downarrow}^{\dagger} c_{\vec{q}\downarrow} c_{\vec{q}\uparrow},$$

where $\varepsilon_{\vec{k}}$ is the single-particle energy, μ –chemical potential $c_{\vec{k}\sigma}^{\dagger}$ ($c_{\vec{k}\sigma}$) denotes creation (annihilation) operator for an spin σ electron in a state $\vec{k}$. The second term describes the scattering of carriers by in-plane while third by out-of-plane impurities. The pair potential $V_{\vec{k}\vec{q}}$ is assumed to take on the separable form $V_{\vec{k}\vec{q}} = -V_0 \phi(\hat{k}) \phi(\hat{q})$ dependent on the wave vector direction $\hat{k} = \frac{\vec{k}}{|\vec{k}|}$. The superconducting order parameter is defined by

$$\Delta(\vec{k}) = \sum_{\vec{q}} V_{\vec{k}\vec{q}} \langle c_{-\vec{q}\downarrow} c_{\vec{q}\uparrow} \rangle \quad (2)$$

and the selfconsistent equation for it, easily derived by the Green's function technique, reads [14]

$$\Delta(\vec{k}) = \sum_{\vec{q}} V_{\vec{k}\vec{q}} \frac{1}{\beta} \sum_{\omega_n} \frac{\tilde{\Delta}(\vec{q})}{\tilde{\omega}_n^2 + (\varepsilon_{\vec{q}} - \mu)^2 + |\tilde{\Delta}(\vec{q})|^2}, \quad (3)$$

where $\tilde{\omega}_n$ and $\tilde{\Delta}(\vec{q})$ are renormalised frequency and order parameter in impure system.

The correction to the self-energy due to impurity scattering $\Sigma_k(i\omega_n) = G_{0k}^{-1} - G_k^{-1}$, where $\omega_n = (2n+1)\pi k_B T_c$ is the Matsubara frequency, G_{0k} and G_k are the Nambu - Gorkov (imaginary time) Green's functions, is calculated here in the Born approximation [14, 15]

$$\Sigma(\vec{k}, i\tilde{\omega}_n) = n_{\text{in}} \sum_{\vec{q}} |V_{\text{in}}(\vec{k} - \vec{q})|^2 \hat{\tau}_3 G_{\vec{q}}(i\tilde{\omega}_n) \hat{\tau}_3$$

$$+ n_{\text{out}} \sum_{\vec{q}} |V_{\text{out}}(\vec{k} - \vec{q})|^2 \hat{\tau}_3 G_{\vec{q}}(i\tilde{\omega}_n) \hat{\tau}_3 \quad (4)$$

where V_{in} and V_{out} represent in-plane and out-of-plane impurity potentials while n_{in} and n_{out} their concentrations. After Kee [16] we assume the out of plane impurity potential to be of short range type $V(\vec{r}) = u_0/(r^2 + d^2)$, where d is the distance of the impurity from conducting plane and u_0 its scattering amplitude. Fourier transform of this potential is expressed in terms of modified Bessel function of the second kind $K_0(d|\vec{k} - \vec{k}'|)$, which is strongly decreasing function of its argument. Therefore we approximate it by constant K_0 for $d|\vec{k} - \vec{k}'| > 1$ and zero otherwise. This means that the momentum transfer $|\vec{k} - \vec{k}'|$ in the scattering process by the out-of-plane impurities is limited to small values. In two-dimensions this translates into small angle scattering. There is no such limitation on the momentum transfer in the scattering by the in-plane impurities. Therefore we take [16, 17]

$$V_{\text{out}}(\vec{q}) = \begin{cases} V_{\text{out}} & \text{for } \phi - \phi' < \theta_c \\ 0 & \text{otherwise} \end{cases}$$

and

$$V_{\text{in}}(\vec{q}) = V_{\text{in}}.$$

In the following we shall calculate the changes of T_c and α due to both kinds of impurities in superconductors.

A. Impurities in d-wave superconductor

Now we specialise the calculations to specific symmetries of the order parameter starting with d -wave one with the order parameter $\Delta(\vec{k}) = \Delta_0 \cos 2\phi$. To proceed we introduce angle dependent density of states (DOS) function $N_F(\phi)$, normalised to its average value, and assume it to be energy independent in the energy window near the Fermi energy. The integrals over $(\varepsilon - \mu)$ can be easily

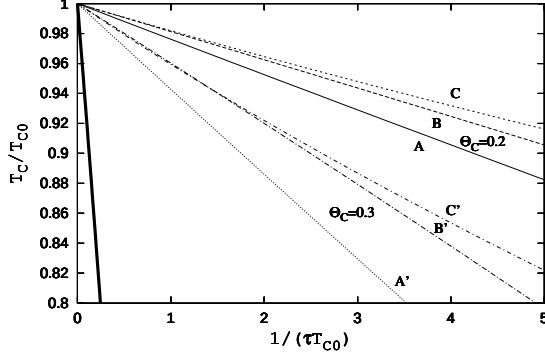


FIG. 1: Effect of in-plane (thick solid line) and out-of-plane impurities (thin lines) in d-wave HTS on T_c for different values of θ_c and for $\frac{1}{2\tau_{in}} = 0$. The two groups of curves correspond to two values of $\theta_c = 0.2, 0.3$, while different labels refer to different angle dependent density of states functions: A and A' are calculated with $N(\phi) = 1$, B and B' with $N(\phi) = \frac{\pi}{2} |\cos 2\phi|$, C and C' with $N(\phi) = \frac{\pi}{2} |\cos 4\phi|$. Note much weaker influence of out-of-plane impurities on T_c .

performed and we find

$$\begin{aligned} \hat{\Sigma}(\vec{k}, i\tilde{\omega}_n) = & -n_{in} V_{in}^2 \int_0^{2\pi} \frac{d\phi'}{2} N_F(\phi') \frac{i\tilde{\omega}_n - \tilde{\Delta}(\phi')\hat{\tau}_1}{\sqrt{\tilde{\omega}_n^2 + \tilde{\Delta}^2(\phi')}} \\ & - n_{out} V_{out}^2 \int_{\phi}^{\phi+\theta_c} \frac{d\phi'}{2} N_F(\phi') \frac{i\tilde{\omega}_n - \tilde{\Delta}(\phi')\hat{\tau}_1}{\sqrt{\tilde{\omega}_n^2 + \tilde{\Delta}^2(\phi')}}. \end{aligned} \quad (5)$$

We are interested in the change of the superconducting transition temperature and simplify the equations by ne-

glecting powers of $\tilde{\Delta}(\phi)$ higher than the first.

Even though it is possible to continue calculation for general $N_F(\phi)$, let us for a moment take $N_F(\phi) = N_F$ independent of ϕ , as is appropriate for the circular Fermi surface, to underline the effect of small angle scattering only. Assuming that $u_n = \frac{\tilde{\Delta}}{|\tilde{\omega}_n|}$ is independent of the angle ϕ we get

$$\begin{aligned} \tilde{\omega}_n - \omega_n = & \left(\frac{1}{2\tau_{in}} + \frac{\theta_c}{2\tau_{out}} \right) \text{sign}\tilde{\omega}_n \\ (\tilde{\Delta} - \Delta_0) \cos 2\phi = & \frac{\tilde{\Delta}}{|\tilde{\omega}_n|} \left(\frac{1}{\tau_{in}} \int_0^{2\pi} d\phi' \cos 2\phi' \right. \\ & \left. + \frac{1}{2\tau_{out}} \int_{\phi}^{\phi+\theta_c} d\phi' \cos 2\phi' \right) \end{aligned} \quad (6)$$

In writing this equation we made use of the fact that $\tilde{\Delta}(\phi) = \tilde{\Delta} \cos 2\phi$ and $\tilde{\Delta}$ does not depend on ϕ for the considered DOS. Vanishing of the integral multiplying $1/\tau_{in}$ in equation (6) for $\tilde{\Delta}$ means that the in-plane impurities are strong pair-breakers in d-wave superconductors. By the same token non-zero value of the integral multiplying $1/\tau_{out}$ means that the out of plane impurities are much weaker pair breakers. This explains [16] the long standing puzzle while dopant impurities do not kill the d-wave superconductivity in HTS.

Performing the integral over ϕ' in the last equation and projecting the result onto $\cos 2\phi$ function we get equation

$$\tilde{\Delta}(\theta_c) - \Delta_0 = \frac{\tilde{\Delta}(\theta_c)}{|\tilde{\omega}_n|} \frac{1}{2\tau_{out}} \left(\frac{\sin 2\theta_c}{2} - tg 2\phi \sin^2 \theta_c \right), \quad (7)$$

which together with that for $\tilde{\omega}_n$ allows us to solve for $u_n(\theta_c) = \frac{\tilde{\Delta}(\theta_c)}{|\tilde{\omega}_n|}$. The result reads

$$u_n = \frac{\Delta_0}{\left| \omega_n + \left(\frac{\theta_c}{2\tau_{out}} + \frac{1}{2\tau_{in}} \right) \text{sign}\omega_n \right| - \frac{1}{2\tau_{out}} \left(\frac{\sin 2\theta_c}{2} - tg 2\phi \sin^2 \theta_c \right)} \quad (8)$$

Gap equation (3) is linearised near T_c and standard manipulations allow us to find the T_c changes due to simultaneous presence of both in-plane and out-of-plane impurities

$$\ln \frac{T_c}{T_{c0}} = -\gamma(\theta_c) \sum_{n=0}^{\infty} \frac{1}{\left(n + \frac{1}{2}\right) \left(n + \frac{1}{2} + \gamma(\theta_c)\right)}, \quad (9)$$

where to lowest non-vanishing order in θ_c

$$\gamma(\theta_c) = \frac{1}{2\tau_{in}\pi k_B T_c} + \frac{1}{2\tau_{out}\pi k_B T_c} \left(\frac{2\theta_c^3}{3} \right)$$

plays a role of pair-breaking parameter. Note, that the first and second order (in θ_c) contributions due to out of plane impurities vanish. This has previously been derived in [16], where the change of the T_c due to the out of plane impurities has been calculated. The equation (9) is valid to all orders in $1/\tau_{in}$ and $1/\tau_{out}$ but to the lowest non-vanishing order in θ_c . It slightly generalizes the previous result [16] to simultaneous presence of in- and out-of-plane impurities. The sum on rhs of equation

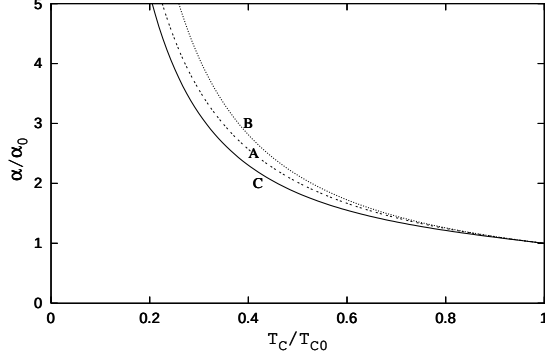


FIG. 2: Effect of the density of states on relative isotope effect. Curve labelled A refers to constant density of states $N(\phi) = 1$, B to $N(\phi) = \frac{\pi}{2} |\cos 2\phi|$ and C to $N(\phi) = \frac{\pi}{2} |\cos 4\phi|$

(9) is expressed *via* digamma function $\psi(z)$ as

$$\ln \frac{T_c}{T_{c0}} = \psi\left(\frac{1}{2}\right) - \psi\left(\frac{1}{2} + \gamma(\theta_c)\right). \quad (10)$$

Figure (1) shows large changes of superconducting transition temperature due to in-plane (thick solid line) and much weaker for out-of-plane impurities for two values of θ_c (thin lines).

For small values of θ_c even strong impurities have negligible effect on T_c . The change of the isotope shift exponent can be easily calculated and found to read

$$\frac{\alpha_0}{\alpha} = 1 - \gamma(\theta_c) \psi'\left(\frac{1}{2} + \gamma(\theta_c)\right). \quad (11)$$

where ψ' denotes the derivative of the di-gamma function. This solution of the impurity problem has been obtained under the assumption of constant (*i.e* angle independent) density of states function $N_F(\phi)$ and scattering rate. The solution of equations (6) with ϕ dependent density of states can also be easily obtained by assuming that $u_n(\phi') = \frac{\Delta(\phi')}{|\omega_n|}$ is slowly varying function of the angle for angles $\phi' \in \langle \phi, \phi + \theta_c \rangle$ and we obtain

$$\ln \frac{T_c}{T_{c0}} = \frac{1}{a_0} \int_0^{\pi/4} d\phi N(\phi) \cos^2 2\phi \left[\psi\left(\frac{1}{2}\right) - \psi\left(\frac{1}{2} + \rho_c(\phi, \theta_c)\right) \right] \quad (12)$$

with the pair breaking parameter

$$\rho_c(\phi, \theta_c) = \frac{1}{2\pi k_B T_c \tau(\phi, \theta_c)} \quad (13)$$

and angle dependent relaxation time $\tau(\phi, \theta_c)$

$$\frac{1}{\tau(\phi, \theta_c)} = \frac{1}{\tau_{\text{in}}} + \frac{1}{\tau_{\text{out}}} \int_{\phi}^{\phi+\theta_c} d\phi' N(\phi') \left(1 - \frac{\cos 2\phi'}{\cos 2\phi}\right) \quad (14)$$

The parameter a_0 is given by

$$a_0 = \int_0^{\pi/4} d\phi N(\phi) \cos^2 2\phi. \quad (15)$$

The first and second terms contributing to $1/\tau(\phi, \theta_c)$ come from frequency renormalization by the in- and out-of-plane impurities respectively, while the third one is due to gap renormalisation by out-of-plane impurities. In-plane impurities do not renormalise the gap, as is seen from equation (6).

The effect of the angle dependent density of states on the suppression of T_c is also illustrated in the figure (1). To facilitate comparisons we have properly normalized

all the densities of states. The observed dependences are easy to understand. Strong changes, with ϕ , of the functions appearing in equation (12) diminish the integral on its *rhs* and this results in a weaker decrease of T_c . Physically it means that due to angular dependence of spectrum the phase space is reduced and scatterers are effectively weaker pair breakers.

Straightforward differentiation leads to the following expression for the isotope coefficient α

$$\frac{\alpha_0}{\alpha} = 1 - \frac{1}{a_0} \int_0^{\pi/4} d\phi N(\phi) \cos^2 2\phi \rho_c(\phi, \theta_c) \psi'\left(\frac{1}{2} + \rho_c(\phi, \theta_c)\right). \quad (16)$$

The effect of angle dependence in $N_F(\phi)$ on isotope coefficient is illustrated in figure (2). It is very small in relatively clean samples (large T_c/T_{c0}) and increases for smaller T_c/T_{c0} . In order to see the simultaneous effect of both types of impurities on the isotope coefficient we have assumed that fraction x of impurities goes into planes while the rest into out-of-plane positions. Assuming that both types of impurities can be characterised by the same value of relaxation rate parameter *i.e.* $\frac{1}{\tau_{\text{in}}} = \frac{1}{\tau_{\text{out}}} = \frac{1}{\tau}$ we

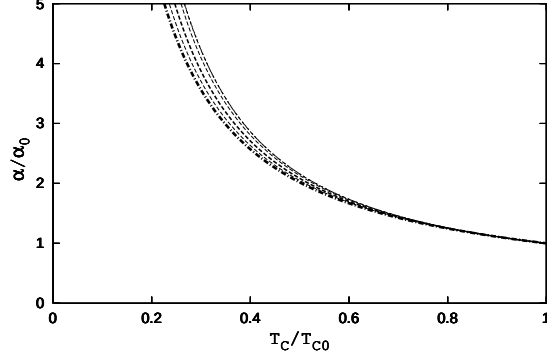


FIG. 3: Simultaneous effect of in-plane and out-of-plane impurities on the isotope coefficient for various values of x (from the bottom curve $x=0.0$, 0.01, 0.03, 0.1, 1.0) which measure the relative contribution of in-plane impurities to the total scattering rate (c.f eq.(17)).

rewrite (14) as

$$\frac{1}{\tau(\phi, \theta_c)} = \frac{1}{\tau} \left[x + (1-x) \int_{\phi}^{\phi+\theta_c} d\phi' N(\phi') \left(1 - \frac{\cos 2\phi'}{\cos 2\phi} \right) \right]. \quad (17)$$

Figure (3) illustrates the changes of α/α_0 with x . Bottom curve in the figure corresponds to $x = 0$ and thus to the changes induced by the out-of-plane impurities while the top one corresponds to the case with all impurities occupying in-plane positions. The assumption $\tau_{in} = \tau_{out}$ is not a realistic one. In fact to get the whole curve for $x = 0$ one has to take unphysically large values of $1/\tau_{out}T_{c0}$.

Figure (4) shows the changes of the normalised isotope coefficient with disorder characterised by the ratio T_c/T_{c0} (solid curve) together with experimental data [18, 19] on $La_{1.85}Sr_{0.15}Cu_{1-x}M_xO_4$ (points). Theoretical line has been calculated for d wave superconductor with $N_F(\phi) = 1$ and angle independent scattering rate. As discussed above angle dependence adds a new degree of freedom.

B. Impurity effects in s -wave layered superconductor

In the s -wave superconductor the order parameter $\Delta(\vec{k}) = \Delta_0$, and nonmagnetic isotropic impurities do change neither T_c nor the isotope coefficient α . This is true for both in-plane and out-of-plane impurities.

Contrary, the magnetic (in-plane) impurities are pair breakers in s -wave superconductors and do change T_c [14,

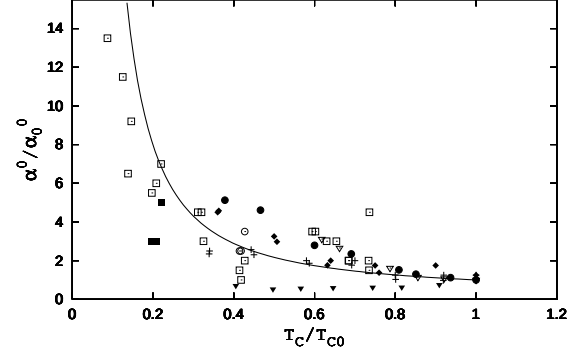


FIG. 4: Solid curve shows the universal dependence of the normalised isotope coefficient *versus* noermlaised transition temperature calculated for the d -wave impure superconductor with constant N_F . The data points are experimental values for a number of materials. Optimally doped $La_{1.85}Sr_{0.15}Cu_{1-x}M_xO_4$ with $M=Co$ (opened triangles), Zn (filled diamonds) and Ni (crosses); over-doped $La_{1.80}Sr_{0.20}Cu_{1-x}M_xO_4$ with $M= Ni$ (filled train-gles), Fe (filled circles)[18]; $Y_{1-x-y}Pr_xCa_yBa_2Cu_3O_{7-\delta}$ with $x=0.2$ and for $y=0.15$ (opened circles), 0.25 (filled squares); $YBa_2(Cu_{1-z}Zn_z)_3O_{7-\delta}$ (opened aquares) [19].

15]

$$\ln \frac{T_c}{T_{co}} = \psi \left(\frac{1}{2} \right) - \psi \left(\frac{1}{2} + \rho_c \right), \quad (18)$$

where $\rho_c = \frac{1}{2\pi k_B T_c \tau_m}$, τ_m is the corresponding magnetic relaxation time. This leads to the changes of the isotope effect

$$\frac{\alpha_0}{\alpha} = 1 - \rho_c \psi' \left(\frac{1}{2} + \rho_c \right). \quad (19)$$

C. Impurity effects of p -wave layered superconductor

The order parameter of the p -wave superconductor is taken here as

$$\Delta(\phi) = \Delta_0 \cos \phi. \quad (20)$$

Repeating the calculations for the in-plane and out-of-plane impurities in p -wave superconductor with constant density of states we get the equations (9-11) with

$$\gamma(\theta_c) = \frac{1}{2\tau_{in}\pi k_B T_c} + \frac{1}{2\tau_{out}\pi k_B T_c} \left(\frac{\theta_c^3}{6} \right).$$

It is important to note that for constant density of states function the calculated changes of the isotope coefficient follow the universal curve independently what is

the cause changing the superconducting transition temperature. The universal α/α_0 vs. T_c/T_{c0} dependence is presented by the curve A in figure (2). Note that numerically this dependence for d -wave superconductor is the same as that obtained for magnetic impurities in s -wave material.

III. ANISOTROPIC MAGNETIC AND NONMAGNETIC IMPURITY POTENTIALS

High temperature superconductors are strongly anisotropic systems with relatively low carrier concentration and layered structure. This means that the screening is not very effective and the impurity - quasiparticle interaction is anisotropic. This motivates the study of anisotropic impurities [20] in HTS. The effect of anisotropic magnetic and nonmagnetic impurities on T_c of superconductors with the general form of the order parameter $\Delta(\vec{k}) = \Delta e(\vec{k})$ have been considered in Ref. [20]. These authors have taken the momentum - dependent impurity potential $u(\vec{k}, \vec{k}') = v(\vec{k}, \vec{k}') + J(\vec{k}, \vec{k}')\vec{S} \cdot \vec{\sigma}$, (where $\vec{S}$ is a classical spin of the impurity and $\vec{\sigma}$ the electron spin density) and assumed a separable form of scattering probabilities

$$v^2(\vec{k}, \vec{k}') = v_0^2 + v_1^2 f(\vec{k})f(\vec{k}') \quad (21)$$

$$J^2(\vec{k}, \vec{k}') = J_0^2 + J_1^2 g(\vec{k})g(\vec{k}') \quad (22)$$

where $v_0(v_1)$, $J_0(J_1)$ are isotropic (anisotropic) scattering amplitudes for non-magnetic and magnetic potentials. $f(\vec{k})$, $g(\vec{k})$ are the momentum - dependent anisotropy functions in the nonmagnetic and magnetic scattering channel, respectively. The averages over the Fermi surface of $f(\vec{k})$ and $g(\vec{k})$ vanish $\langle f(\vec{k}) \rangle_{\text{FS}} = 0$ and are normalised as $\langle f^2(\vec{k}) \rangle_{\text{FS}} = 1$. The change of transition temperature calculated in the Born approximation is given in [20] and the isotope effect is found to be

$$\begin{aligned} \frac{\alpha_0}{\alpha} = & 1 - (1 - \langle e \rangle^2 - \langle ef \rangle^2) \cdot \\ & \cdot \left(\frac{\Gamma_0 + G_0}{2\pi k_B T_c} \right) \psi' \left(\frac{1}{2} + \left(\frac{\Gamma_0 + G_0}{2\pi k_B T_c} \right) \right) \\ & - \langle ef \rangle^2 \left(\frac{\Gamma_0 + G_0 + G_1 - \Gamma_1}{2\pi k_B T_c} \right) \cdot \\ & \cdot \psi' \left(\frac{1}{2} + \frac{\Gamma_0 + G_0 + G_1 - \Gamma_1}{2\pi k_B T_c} \right) \\ & - \langle e \rangle^2 \left(\frac{2G_0}{2\pi k_B T_c} \right) \psi' \left(\frac{1}{2} + \frac{2G_0}{2\pi k_B T_c} \right), \quad (23) \end{aligned}$$

where $\Gamma_0 = \pi n_i N_0 v_0^2$, $\Gamma_1 = \pi n_i N_0 v_1^2$, $G_0 = \pi n_i N_0 J_0^2 S(S+1)$ and $G_1 = \pi n_i N_0 J_1^2 S(S+1)$ are the respective scattering rates. The dependence of α/α_0 on T_c/T_{c0} has been shown in Fig.(5). The value of anisotropy of the $\langle ef \rangle^2$ and the scattering Γ_1 present new degrees of freedom which can be used to fit experimental data. The universality seen for isotropic scattering is lost in these scenario.

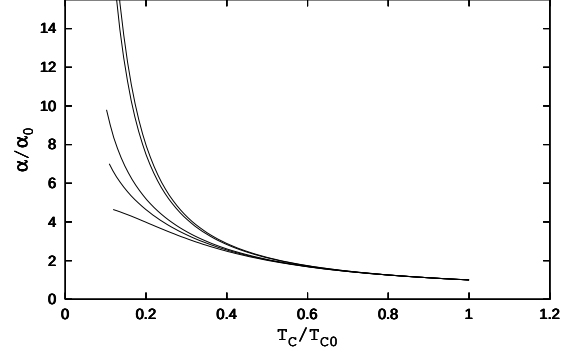


FIG. 5: The isotope coefficient of d -wave superconductor ($\langle e \rangle = 0.0$), for different values of the normalized anisotropic scattering rate (from top): $\Gamma_1/\Gamma_0 = 0.0, 0.5, 0.9, 0.95, 1.0$. We have taken $\langle ef \rangle^2 = 0.2$ and assumed non-magnetic impurities.

IV. COMPARISON WITH EXPERIMENTS

Let us start the comparison of the obtained results with existing experimental data with a word of caution. There may exist a number of factors which can affect the value of isotope coefficient of the impure system α . In particular electron-phonon interaction and the phonon spectrum may change after the impurity doping. We do not take such effects into account.

We have also implicitly assumed that electron-phonon interaction does play a role in driving the superconducting instability of the system and makes the clean material coefficient α_0 non-zero albeit it may take on very small value. This, however, seem to be well established by various experimental techniques [21], [22].

Here we concentrate on the oxygen isotope effect, but it has to be noted that interesting results have also been obtained in the studies of copper isotope substitutions. The negative value of α_{Cu} observed in some underdoped $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$ samples [6], [7] have been recently explained [23] as due to scattering of electrons by low-frequency phonons with large momenta. It is to be checked whether the same mechanism is responsible for negative oxygen isotope effect in very clean Sr_2RuO_4 p -wave superconductor [24].

The oxygen isotope shift in high temperature superconductors does depend on the concentration of carriers. The explanation of this dependence has been a subject of number of papers [25]-[30]. The authors invoke such effects as: anharmonicity, zero point motion, mass dependence of carrier concentration, energy dependence of the density of states, opening of the normal state pseudo-gap and the T_c changes due to impurities.

In the present work we contribute to the elucidation of the role played by various impurities in changing T_c and α of superconductors. Because the T_c reduction due to dopant impurities like Sr in $La_{2-x}Sr_xCuO_4$ is small their influence on α follows the standard curve like one presented in the figure (4). The departures would be seen for smaller ratio of T_c/T_{c0} as is evident from figure (3). Small values of θ_c which reflect weaker pair breaking character of out-of-plane impurities does not influence the slope of the α/α_0 vs. T_c/T_{c0} curve. Isotope changes due to impurities in systems with the same bare scattering rate but with differing values of θ_c follow the same universal curve.

On the other hand the effect of anisotropic impurity scattering changes the universal dependence. Isotope coefficients of the systems with various degree of anisotropy follow slightly differing curves. This additional degree of freedom allows for a better fit to the experimental data. The fit, however is ambiguous. The same changes can be induced by anisotropy of scattering and the anisotropy of the order parameter.

V. ISOTOPE EFFECT IN IMPURE STRIPED CUPRATES

The strong sensitivity of T_c to in-plane impurities in high temperature superconductors, independently on their magnetic nature, and the difficulties of the existing theories to fully describe the wealth of experimental data has resulted in new approaches to the problem. In a recent work Morais Smith and coworkers [31] have developed the scenario of T_c suppression by Zn impurities, based on the stripe picture of high T_c oxides. Assuming that the doped Zn does not affect the superfluid density the authors considered the increase of local inertia of the stripe due to pinning forces and local slowing down of their dynamics. The calculations within this model give, in agreement with experimental findings, the suppression of T_c which is linear in the concentration of impurities z . It also gives the quadratic dependence of critical Zn concentration z_c (z_c is concentration at which superconductivity disappears) on the superconducting transition temperature of Zn free ('clean') systems T_{c0} .

The resulting formula for T_c suppression in the regime of incompressible stripes is [31]

$$\frac{T_c}{T_{c0}} = 1 - \frac{\gamma z}{T_{c0}^2}, \quad (24)$$

where z is concentration of Zn (or other in-plane impurities), γ is a factor depending *inter alia* on the stripe distance and lattice constant a . In the optimally doped and overdoped region, where charged stripes behave as an compressible quantum fluid the T_c reduction has been found to be universal and given by

$$\frac{T_c}{T_{c0}} = 1 - \frac{z}{z_c}. \quad (25)$$

with constant z_c .

In the stripe senario we find that the change of isotope coefficient due to impurities reads

$$\alpha/\alpha_0 = \frac{2}{(T_c/T_{c0})} - 1 \quad (26)$$

in the incompressible region and

$$\alpha/\alpha_0 = 1 \quad (27)$$

in the compressible region.

Roughly inverse dependence of α/α_0 on T_c/T_{c0} at low T_c is in good qualitative agreement with experimental data (cf. figure (4)) and gives credit to the stripe picture of superconductivity in this material.

It is, however, hard to explain the difference between Fe and Ni substitution to the otherwise overdoped $La_{1.85}Sr_{0.15}CuO_4$ sample. According to the theory [31] one expects in this material incommensurate stripes and thus no influence of impurities on both T_c and α . The difficulty arises from the fact that both impurities (Ni and Fe) do change the transition temperature but the isotope shift is nearly constant for Ni substitution. One explanation is that concentration of carriers may change in the doping process. The divalent Ni does not change the concentration and the position of the Fermi level remains roughly constant while trivalent Fe ions change it driving the system effectively into underdoped or optimally doped regime. If this is true the Fe doped system is thus expected, within stripe scenario, to change both T_c and α . It is obvious that the isotope coefficient α of impure

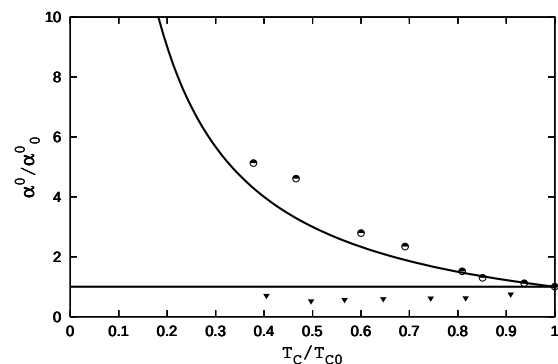


FIG. 6: The isotope effect in impure striped cuprates: the continuous line is given by Eq. (26,27). The data points are experimental values for overdoped $La_{1.80}Sr_{0.20}Cu_{1-x}M_xO_4$, with Ni (filled triangles), Fe (circles) [18].

system can take non-zero values only for those systems for which T_{c0} depends on isotope mass and $\alpha_0 \neq 0$. The question thus arises whether the formation of stripes and

the driving mechanism of superconductivity in striped metal are of purely electronic origin or electron-phonon interaction plays the role to make $\alpha_0 \neq 0$. These issues have been recently addressed [32]. The XANES experiments revealed large oxygen isotope effect on the stripe formation temperature T^* , as also on effective supercarrier mass. This shows that electron phonon interaction does play a role in a stripe model of superconductivity and validates the above analysis and conclusions.

VI. CONCLUSIONS

We have studied the effect of various impurities on the isotope coefficient α . While the in-plane and out-of-plane impurities affect the superconducting transition temperature quite differently (*c.f.* Fig. 1), their influence on α is universal for angle independent scattering relaxation rate and density of states function.

Experimental changes of α/α_0 with T_c/T_{c0} for a num-

ber of high temperature copper oxides can be well described solely by the effect of impurities on d -wave superconductors. The angle dependence of relaxation rate and $N_F(\phi)$ or the simultaneous presence of anisotropic scatterers of magnetic and non-magnetic nature adds new degrees of freedom which can be used to quantitatively describe the data.

These mechanisms of T_c and α changes operate for both dopant (like *Sr*) and extra impurities (like *Ni* or *Zn*). However, they do not differentiate between underdoped and overdoped systems. On the other hand the stripe model of superconductivity describes the detrimental effect of *Ni* or *Zn* on T_c . The stripe theory predicts increase of α with impurity concentration on the underdoped side of the phase diagram and no change of it in the overdoped region. This agrees with data [18] on *Ni* and *Fe* doped $La_{1.80}Sr_{0.20}Cu_{1-x}Ni(Fe)_xO_4$.

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